



## DC Input 4-Pin Half Pitch Mini-Flat Phototransistor Optocoupler

### Features

- High isolation 3750 V<sub>RMS</sub>
- Multiple CTR selection available
- DC input with transistor output
- Operating temperature range - 55 °C to 125 °C
- RoHS compliance
- REACH compliance
- Halogen compliance
- Regulatory Approvals
  - UL - UL1577 (E364000)
  - VDE - EN60747-5-5(VDE0884-5)
  - CQC – GB4943.1, GB8898
  - IEC60065, IEC60950

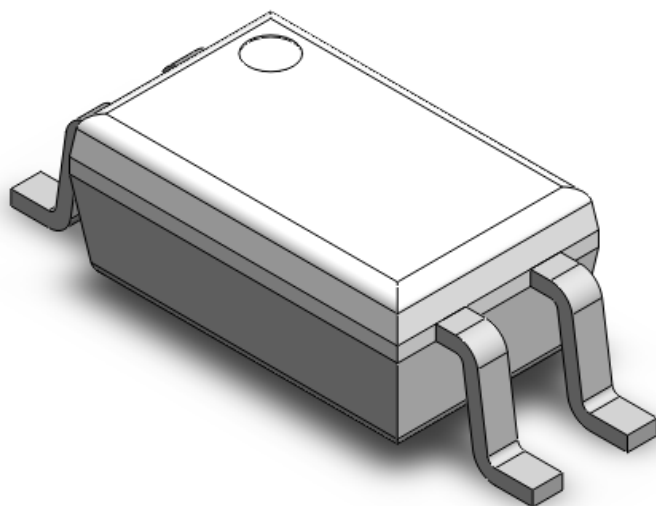
### Description

These series of general purpose optocoupler consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead half pitch Mini-Flat package.

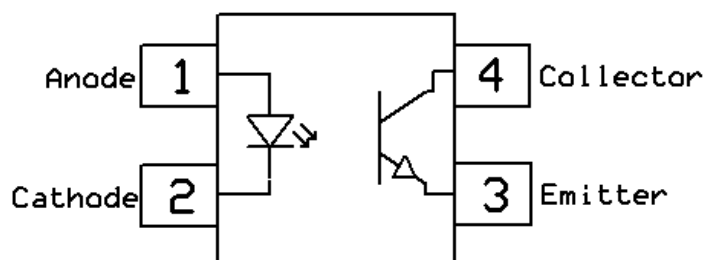
### Applications

- DC-DC Converters
- Programmable controllers
- Telecommunication equipment
- Hybrid substrates that require high density mounting

### Package Outline



### Schematic





# CTH217 Series

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### Absolute Maximum Rating at 25°C

<b>Symbol</b>	<b>Parameters</b>	<b>Ratings</b>	<b>Units</b>	<b>Notes</b>
V <sub>ISO</sub>	Isolation voltage	3750	V <sub>RMS</sub>	
T <sub>OPR</sub>	Operating temperature	-55 ~ +125	°C	
T <sub>STG</sub>	Storage temperature	-55 ~ +150	°C	
T <sub>SOL</sub>	Soldering temperature	260	°C	
P <sub>TOT</sub>	Total power dissipation	200	mW	
<b>Emitter</b>				
I <sub>F</sub>	Forward current	50	mA	
I <sub>F(TRANS)</sub>	Peak transient current (≤1μs P.W,300pps)	1	A	
V <sub>R</sub>	Reverse voltage	6	V	
P <sub>D</sub>	Power dissipation	70	mW	
<b>Detector</b>				
P <sub>C</sub>	Power dissipation	150	mW	
B <sub>VCEO</sub>	Collector-Emitter Breakdown Voltage	80	V	
B <sub>VECO</sub>	Emitter-Collector Breakdown Voltage	7	V	
I <sub>C</sub>	Collector Current	50	mA	



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### Electrical Characteristics $T_A = 25^\circ\text{C}$ (unless otherwise specified)

#### Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$V_F$	Forward voltage	$I_F = 10\text{mA}$		1.24	1.4	V	
$I_R$	Reverse Current	$V_R = 6\text{V}$	-	-	5	$\mu\text{A}$	
$C_{IN}$	Input Capacitance	$f = 1\text{MHz}$	-	10	-	pF	

#### Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$B_{V_{CEO}}$	Collector-Emitter Breakdown	$I_C = 0.1\text{mA}$	80	-	-	V	
$B_{V_{ECO}}$	Emitter-Collector Breakdown	$I_E = 0.1\text{mA}$	7	-	-	V	
$I_{CEO}$	Collector-Emitter Dark Current	$V_{CE} = 20\text{V}, I_F = 0\text{mA}$	-	-	100	nA	

#### Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
CTR	Current Transfer Ratio	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$	50		600	%	
			80		160		
			130		260		
			200		400		
			300		600		
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage	$I_F = 20\text{mA}, I_C = 1\text{mA}$	-	0.1	0.2	V	
$R_{IO}$	Isolation Resistance	$V_{IO} = 500\text{V}_{DC}$	$5 \times 10^{10}$			$\Omega$	
$C_{IO}$	Isolation Capacitance	$f = 1\text{MHz}$		0.5	1	pF	

#### Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$t_r$	Rise Time	$I_C = 2\text{mA}, V_{CE} = 2\text{V}, R_L = 100\Omega$	-	6	-	$\mu\text{s}$	
$t_f$	Fall Time		-	8	-		



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### Typical Characteristic Curves

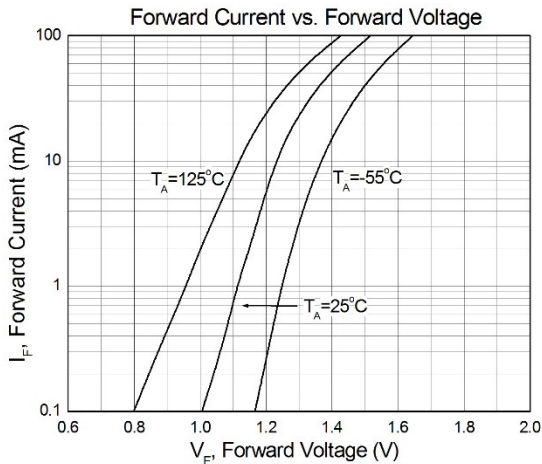


Figure 1

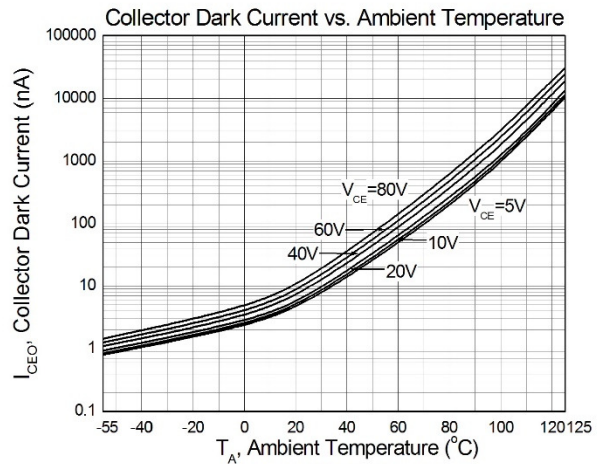


Figure 2

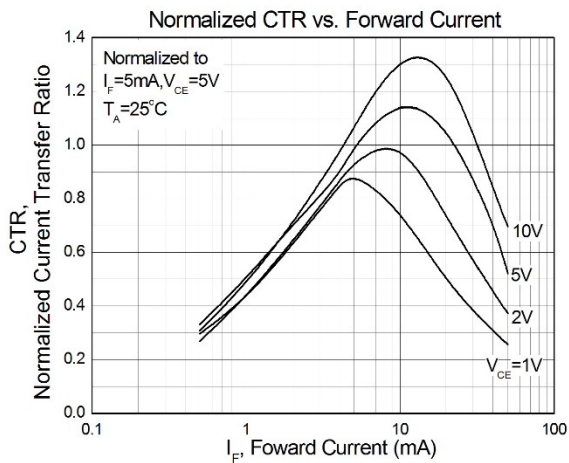


Figure 3

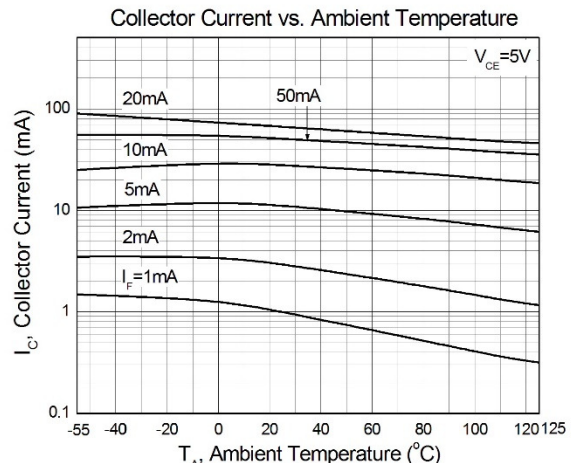


Figure 4

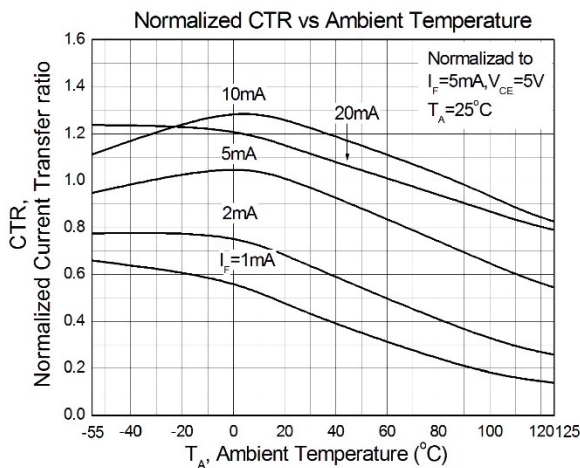


Figure 5

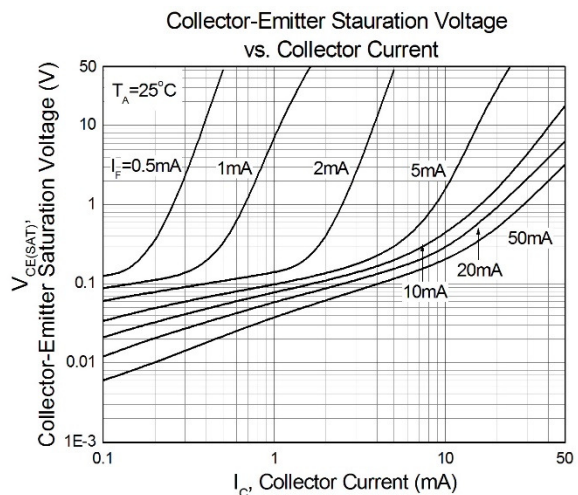
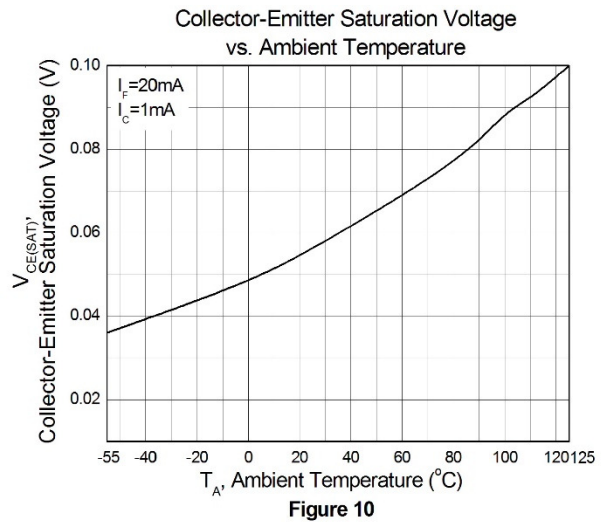
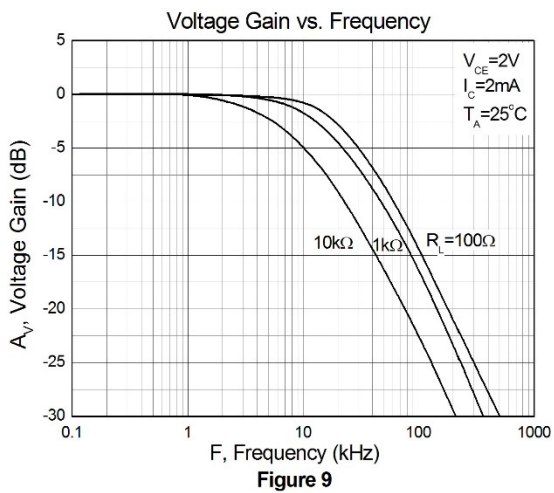
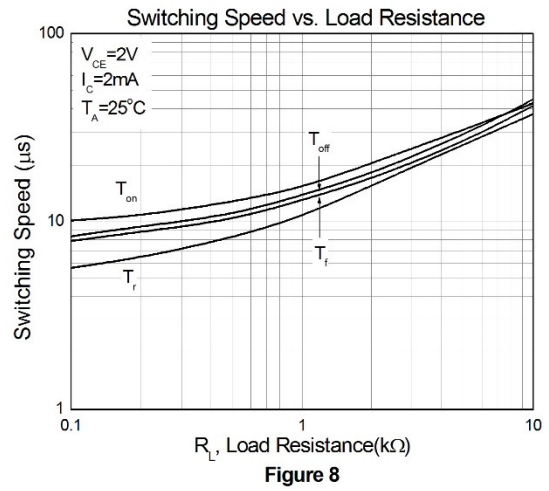
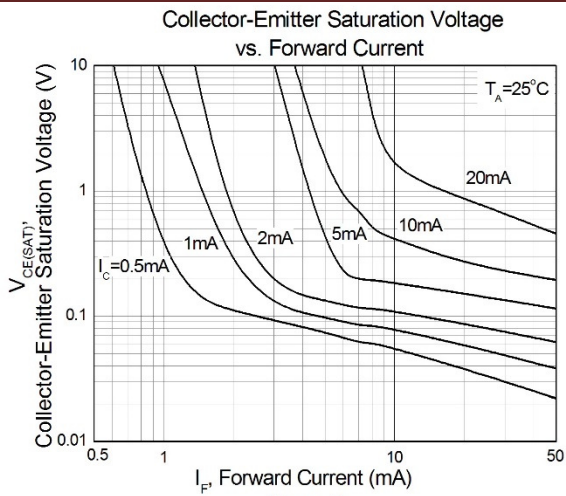


Figure 6



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## DC Input 4-Pin Half Pitch Mini-Flat Phototransistor Optocoupler



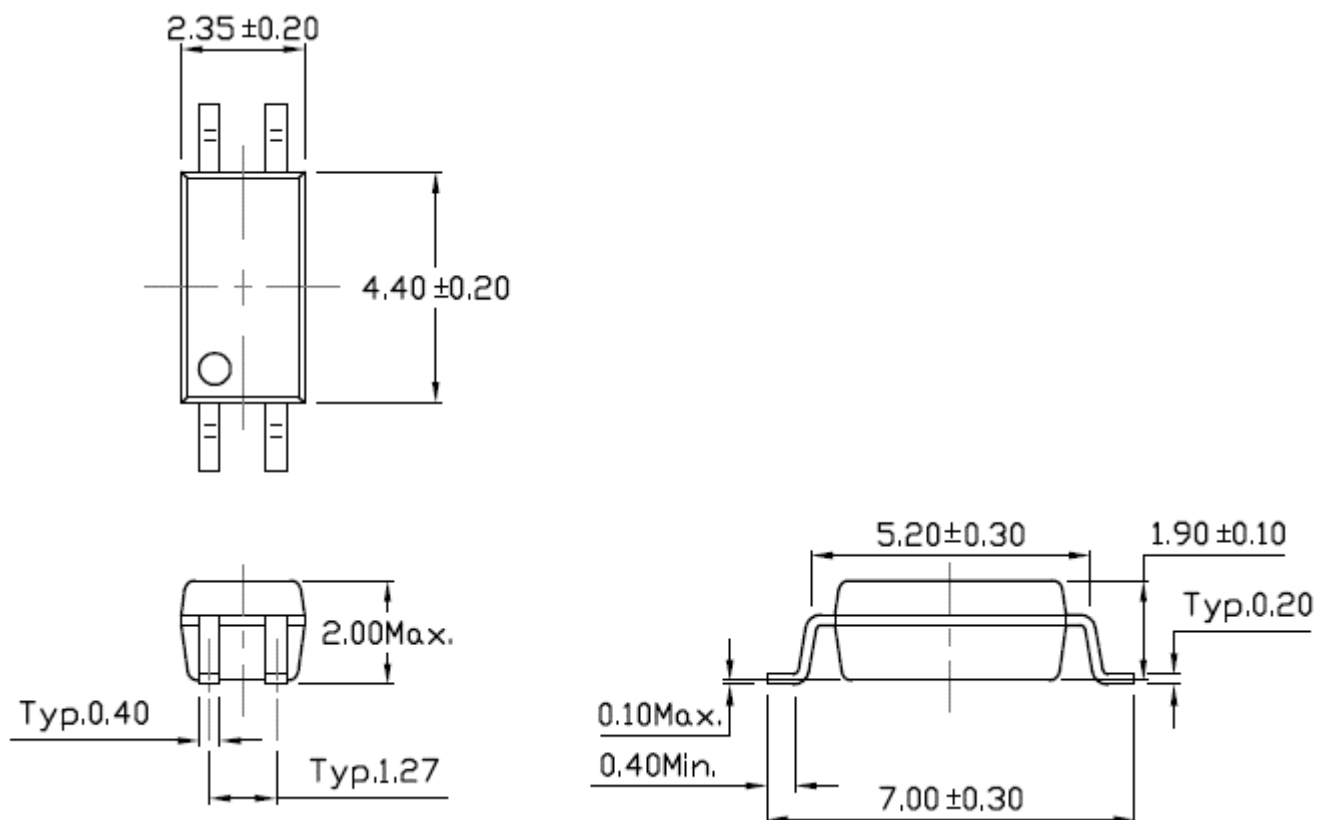


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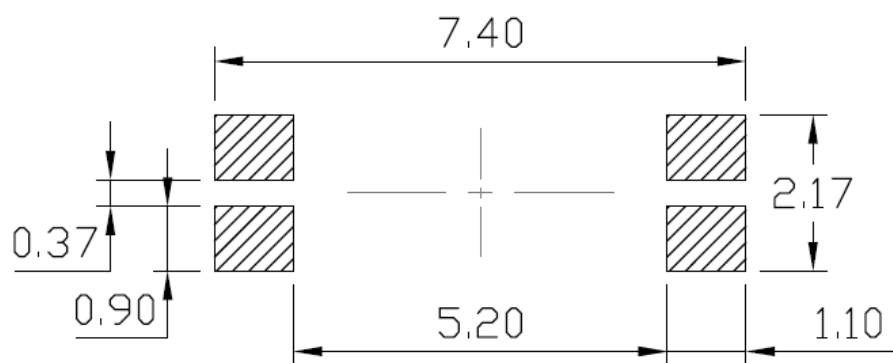
## DC Input 4-Pin Half Pitch Mini-Flat

### Phototransistor Optocoupler

#### Package Dimension *Dimensions in mm unless otherwise stated*



#### Recommended Solder Mask *Dimensions in mm unless otherwise stated*

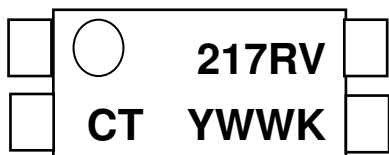




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## DC Input 4-Pin Half Pitch Mini-Flat Phototransistor Optocoupler

### Marking Information



#### Note:

- CT : Denotes "CT Micro"
- 217 : Product Number
- R : CTR Rank
- V : VDE Option
- Y : Fiscal Year
- WW : Work Week
- K : Manufacturing Code

### Ordering Information

#### CTH217X(V)(Z)

X = Part No. (X=A, B, C, D or none)

V = VDE Option (V or none)

Z = Tape and reel option (T1 or T2)

<b>Option</b>	<b>Description</b>	<b>Quantity</b>
T1	Surface Mount Lead Forming – With Option 1 Taping	5000 Units/Reel
T2	Surface Mount Lead Forming – With Option 2 Taping	5000 Units/Reel



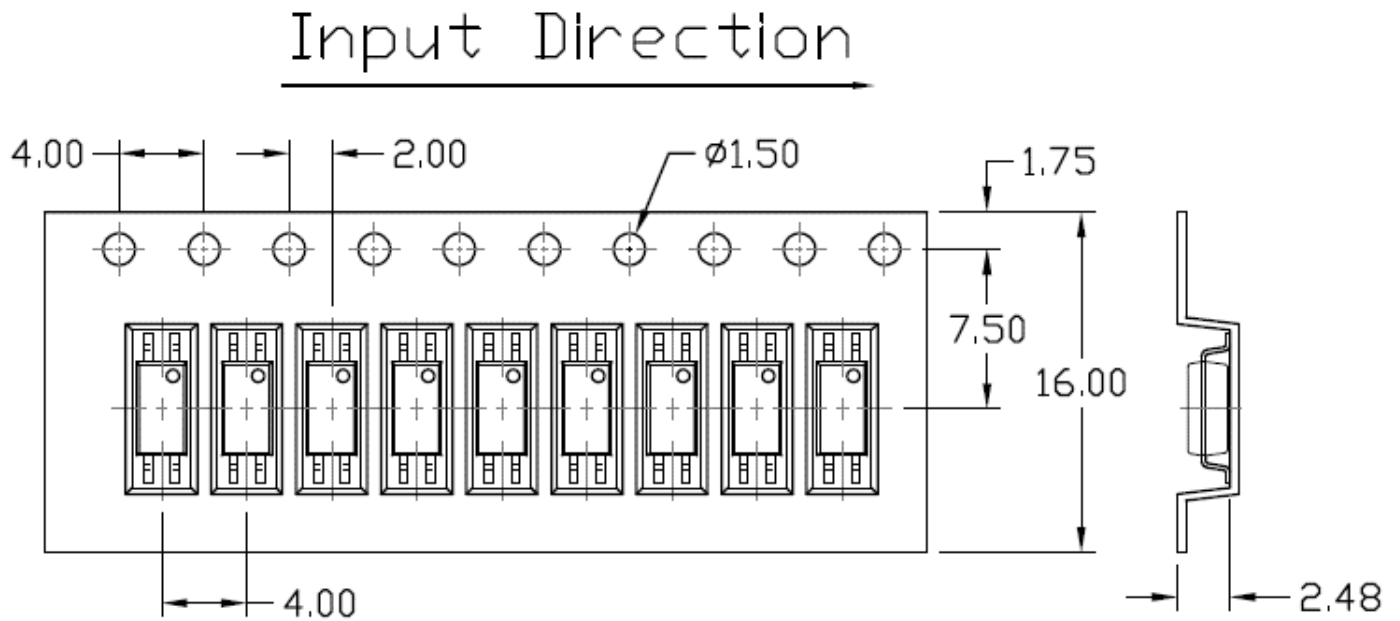
# CTH217 Series

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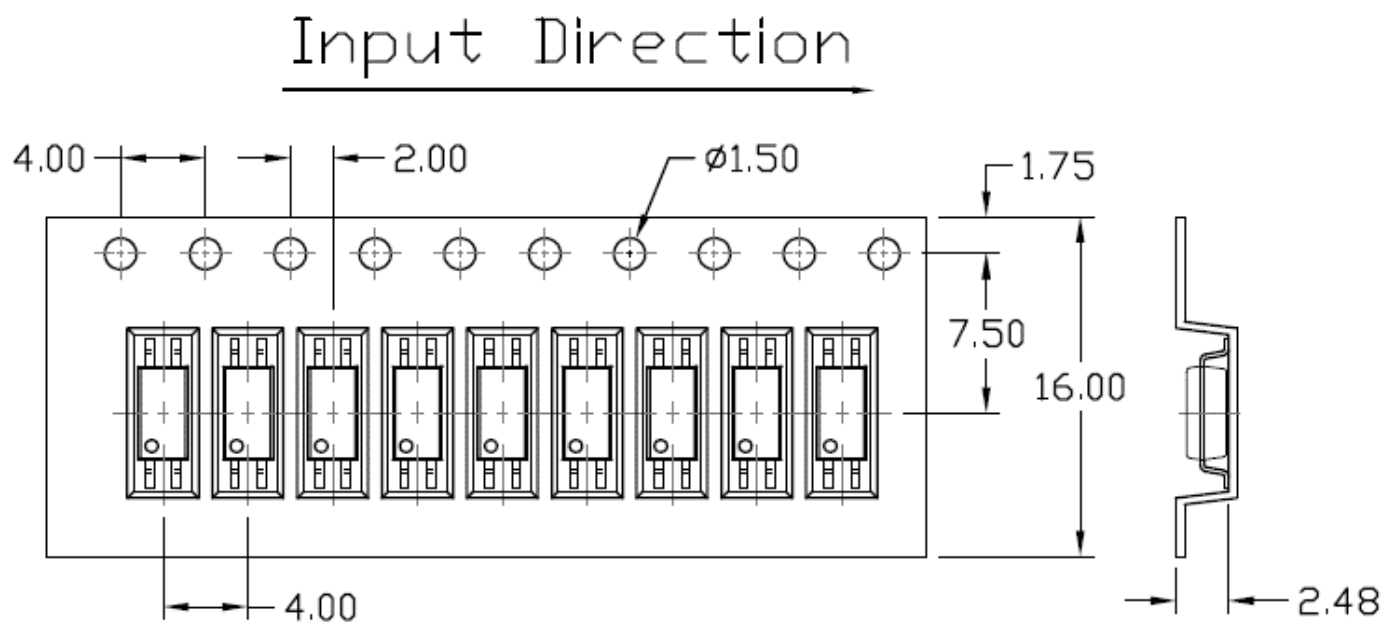
### Phototransistor Optocoupler

#### Carrier Tape Specifications *Dimensions in mm unless otherwise stated*

##### Option T1



##### Option T2



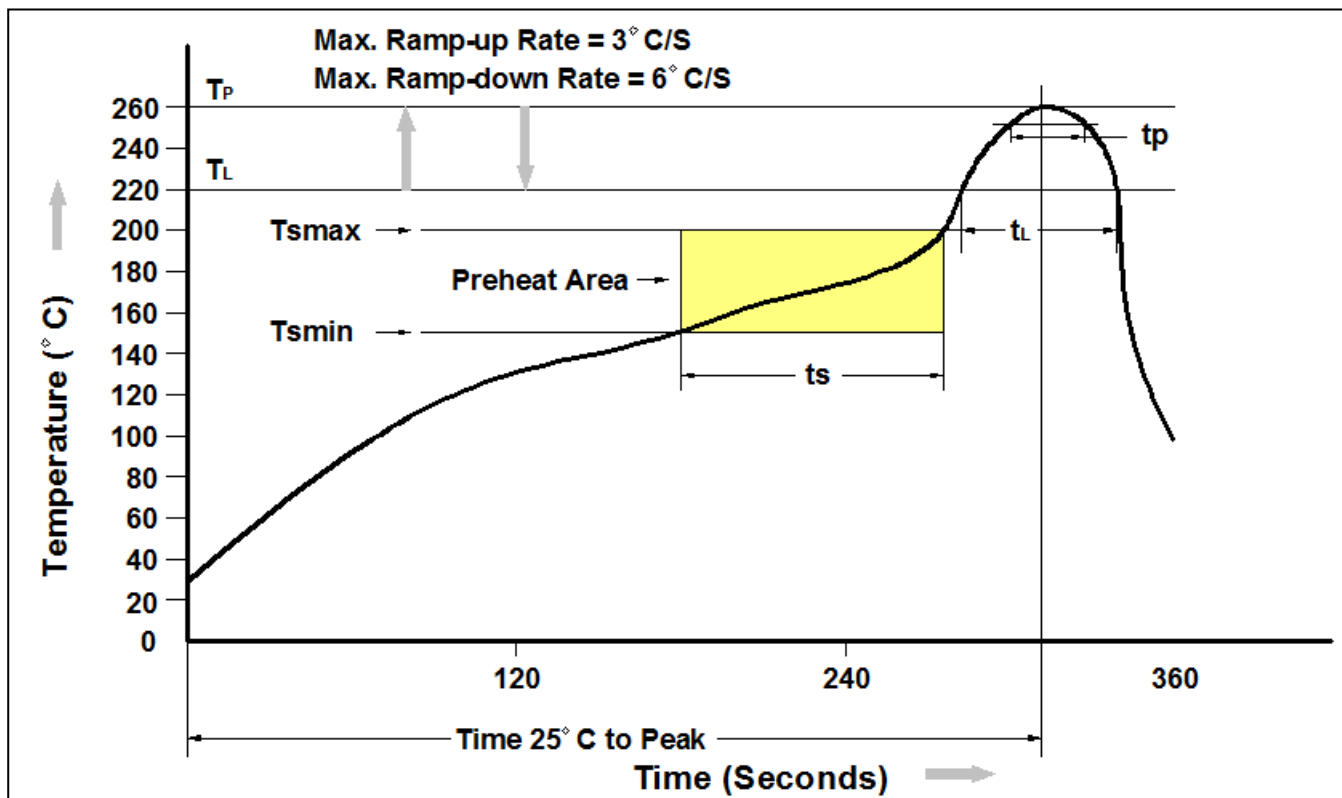




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### Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T <sub>smin</sub> )	150 °C
Temperature Max. (T <sub>smax</sub> )	200 °C
Time (t <sub>s</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60-120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.
Liquidous Temperature (T <sub>L</sub> )	217 °C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260 °C +0 °C / -5 °C
Time (t <sub>P</sub> ) within 5 °C of 260 °C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max
Time 25 °C to Peak Temperature	8 minutes max.



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